Solutions: part 4

Largest area? $I_o = 10 \text{ uA}$.

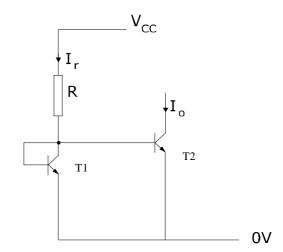
Consider T_1 biggest, then $I_r = 50 \text{ uA}$

$$R = \frac{30 - 0.7}{50uA} = 586k\Omega$$

if T_2 biggest, $I_r = 10uA/5 = 2uA$

giving
$$R = \frac{30 - 0.7}{2uA} = 14.7M\Omega$$
 !!

- enormous for an I.C.



Make T₁ biggest.

R is still very large for an I.C. (would take up a massive area).

Second circuit (Resistors must be < 50k)

Ignore base currents ($I_C \sim I_E$)

$$I_r R_1 + V_{BE1} = I_o R_2 + V_{BE2}$$

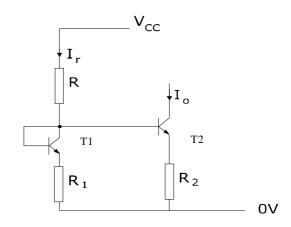
$$I_{o}R_{2} - I_{r}R_{1} = V_{RE1} - V_{RE2}$$

$$\frac{I_o R_2}{I_r R_1} - 1 = \frac{1}{I_r R_1} \left(V_{BE1} - V_{BE2} \right)$$
 (1)

$$I_r = I_S \exp\left(\frac{V_{BE1}}{V_T}\right)$$

$$I_O = I_S \exp\left(\frac{V_{BE2}}{V_T}\right)$$

so
$$\frac{I_o R_2}{I_o R_1} - 1 \approx \frac{V_T}{I_o R_1} \ln \left(\frac{I_r}{I_o} \right)$$



Given that $I_r = 1$ mA, $I_o = 10$ uA, which resistor biggest (R_1 or R_2)?

Looking at Eqn.1, expect V_{BE} difference to be small so expect $\frac{I_o R_2}{I_r R_1} - 1 \approx 0$

$$\frac{I_o}{I_r} \approx \frac{R_1}{R_2}$$
, $\frac{10uA_o}{1mA} \approx \frac{R_1}{R_2}$, $R_1 \sim 0.01 R_2$ so consider making R_1 the smaller.

(2)

Want resistors less than 50k, make $R_2 = 25k$ (say) so $R_1 \sim 250\Omega$.

Get more accurate values: set $R_1 = 250\Omega$,

$$R_1 = 250\Omega$$
,

Use Eqn.2,
$$R_2 \approx \frac{V_T}{I_o} \ln \left(\frac{I_r}{I_o} \right) + \frac{I_r}{I_o} R_1 = 11,512 + 25,000 = 36.5 \text{k}\Omega$$
 $\mathbf{R}_2 = \mathbf{36.5 k}\Omega$

Finally need to find R: volt drop across R_1 is $I_rR_1 = 0.25V$ so voltage at collector/base node of T_1 is 0.7V + 0.25V = 0.95V

$$R = \frac{30 - 0.95}{1mA} \sim 30k\Omega$$

$$\mathbf{R} = 30k\Omega$$

ALL RESISTORS LESS THAN $50k\Omega$

Note this is a DESIGN so there are other answers that will satisfy the given requirements (specification).